



# SA12B5 SA16B3 / SA16B6 SCHOTTKY ARRAYS

Application Specific Discretes  
A.S.D.™

## MAIN APPLICATIONS

Any electronic equipment where suitable bus termination is required to avoid signal reflections and distortions :

- PCs
- Workstations
- High frequency processor boards
- Dataline interface

## DESCRIPTION

Dedicated to bus termination, the Schottky arrays SA12B5, SA16B3 and SA16B6 minimise stray emissions from PCB tracks. They provide suitable termination by avoiding signal reflexions and distortions.

## FEATURES

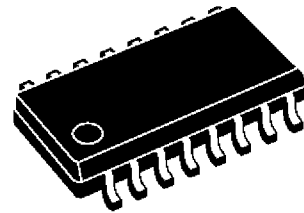
- 12-BIT (SA12) OR 16-BIT (SA16) DUAL SCHOTTKY DIODE ARRAYS
- REVERSE VOLTAGE :  $V_{RRM} = 7.5 \text{ V}$
- FORWARD VOLTAGE  $V_F < 1.3 \text{ V}$

## BENEFITS

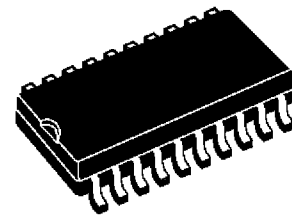
- Provides impedance matching, and minimizes distortion.
- Lowers EMI / RFI radiation.
- Eliminates negative voltage : minimizes risk of latch-up for sensitive ICs.
- Saves valuable space on board.

## COMPLIES WITH FOLLOWING STANDARD :

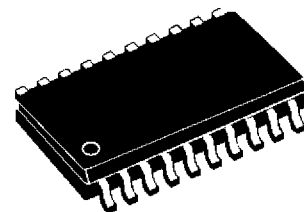
- MIL STD 883C - Method 3015-6 - class 3
- IEC1000-4-2 level 4



SO-16



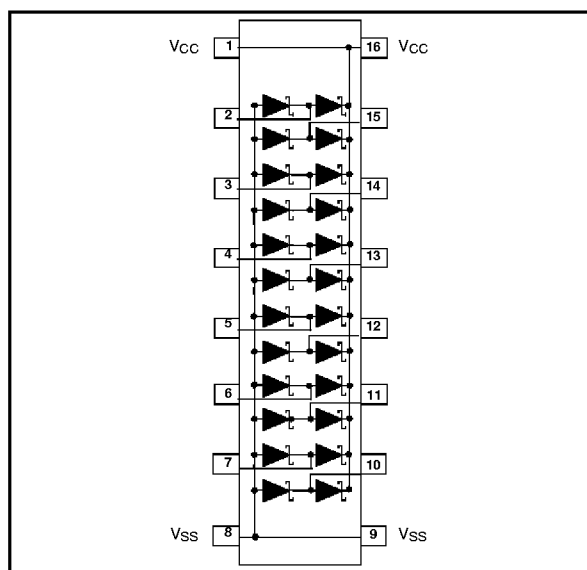
SO-20



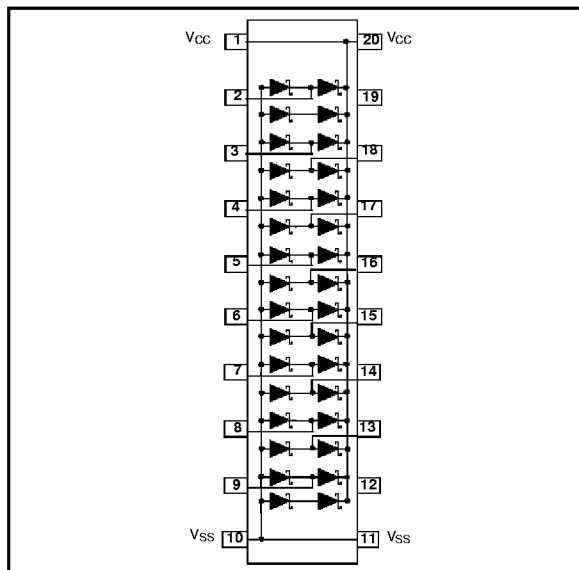
SSOP20

# SA12B5 / SA16B3 / SA16B6

## FUNCTIONAL DIAGRAM (SO-16)



## FUNCTIONAL DIAGRAM (SO-20 and SSOP20)



### ABSOLUTE MAXIMUM RATINGS ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ )

Symbol	Parameter and test conditions		Value	Unit
P	Power dissipation	SO-20 SO-16 and SSOP20	1250 850	mW
$V_{OP}$	Maximum operating voltage ( $V_{CC} - V_{SS}$ )		7.5	V
$V_{PP}$	Maximum electrostatic discharge MIL STD 883C - Method 3015-6 / IEC1000-4-2 contact		8	kV
$T_{op}$	Operating temperature range (see note 1)		-40 to +85	$^{\circ}\text{C}$
$T_{stg}$	Storage temperature range		-55 to +150	$^{\circ}\text{C}$
$T_L$	Maximum lead temperature for soldering during 10s		260	$^{\circ}\text{C}$
$T_j$	Maximum junction temperature		150	$^{\circ}\text{C}$

Note 1: within the  $T_{op}$  range, the SAxx keep on operating. The impacts of the ambient temperature are given by derating curves on the following page.

### ELECTRICAL CHARACTERISTICS ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ )

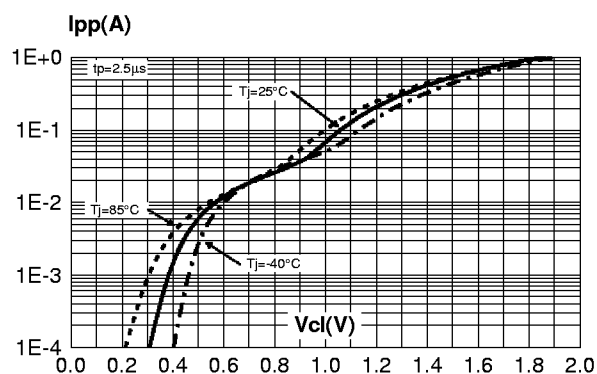
Symbol	Parameter and test conditions		Typ.	Max.	Unit
$I_R$	Leakage current @ $V_{RRM} = 7.5\text{ V}$			5	$\mu\text{A}$
$V_F$	Forward voltage (see note 2)	$I_{PP} = 18\text{ mA}$ $I_{PP} = 50\text{ mA}$		1.05 1.3	V
$C_d$	Capacitance	$V_{bias} = 0\text{ V}$ , $F = 1\text{ MHz}$		16	pF

Note 2: for both pull-up and pull-down schottky diodes.

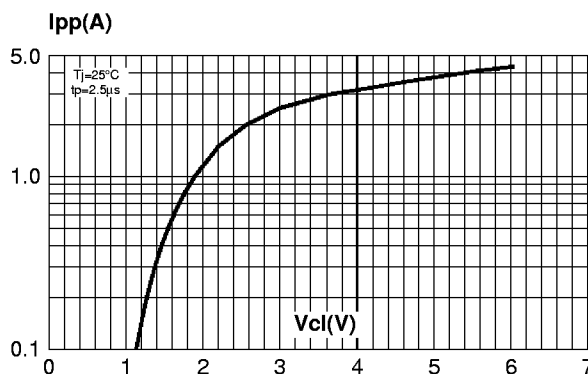
### THERMAL RESISTANCE

Symbol	Parameter	Packages	Value	Unit
$R_{th(j-a)}$	Junction to ambient	SO-16 and SSOP20 SO-20	140 100	$^{\circ}\text{C/W}$

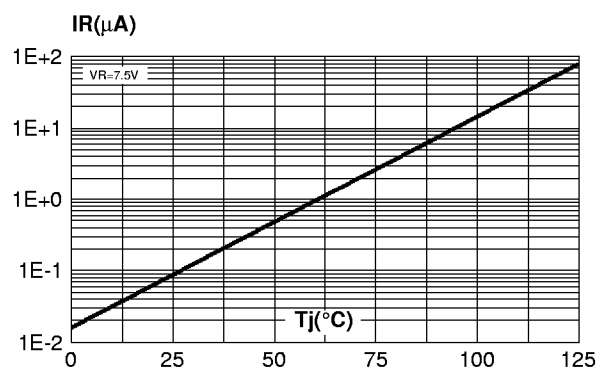
**Fig1-1:** Clamping forward voltage versus peak pulse current (typical values, low level).



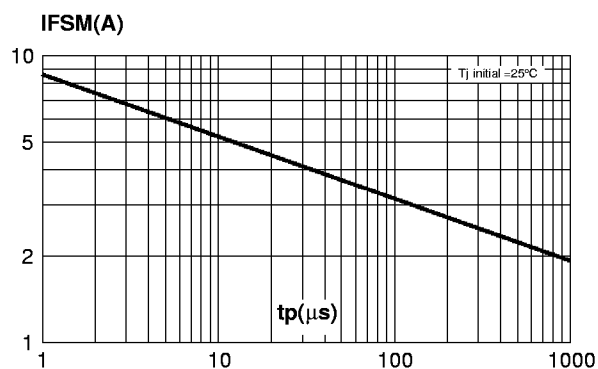
**Fig1-2:** Clamping forward voltage versus peak pulse current (typical values, high level).



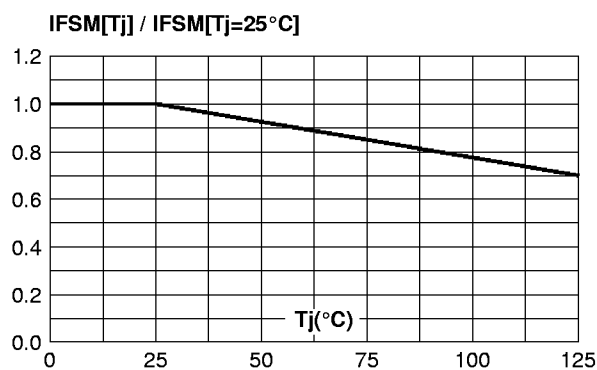
**Fig 2:** Leakage current versus junction temperature (typical values).



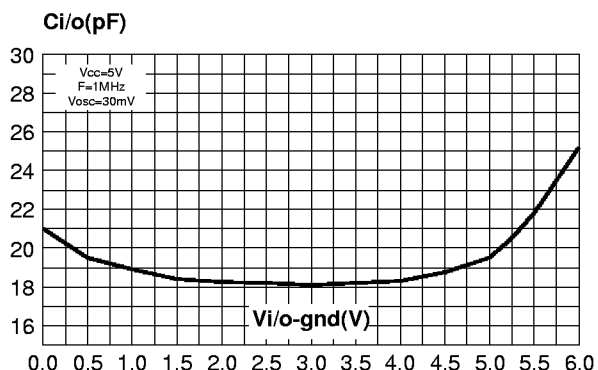
**Fig 3:** Non repetitive surge peak forward current versus pulse duration (rectangular waveform).



**Fig 4:** Non repetitive surge peak forward current versus initial junction temperature.

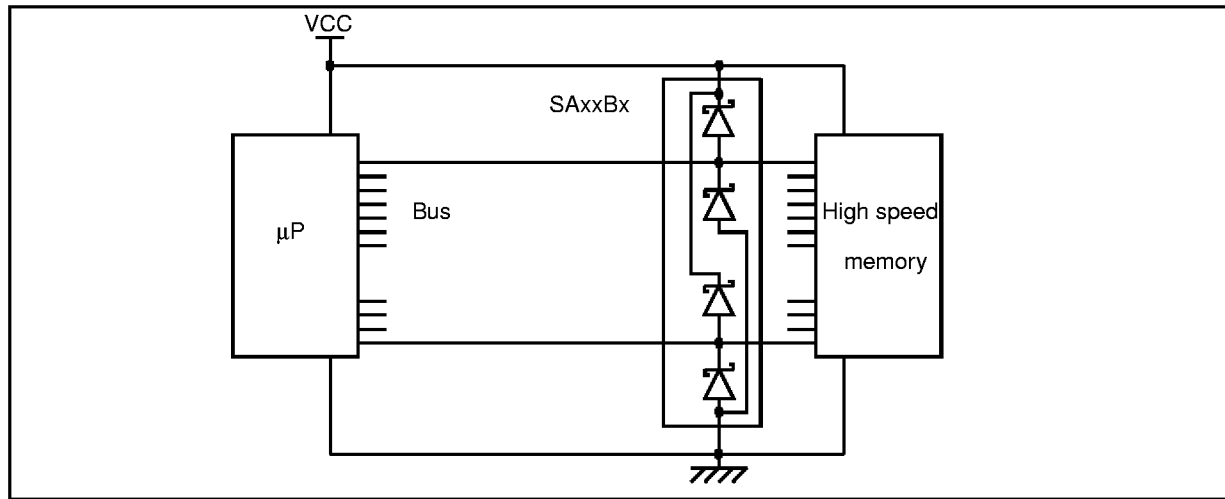


**Fig 5:** Capacitance between input or output and ground versus applied voltage (typical values).



# SA12B5 / SA16B3 / SA16B6

## TYPICAL APPLICATION

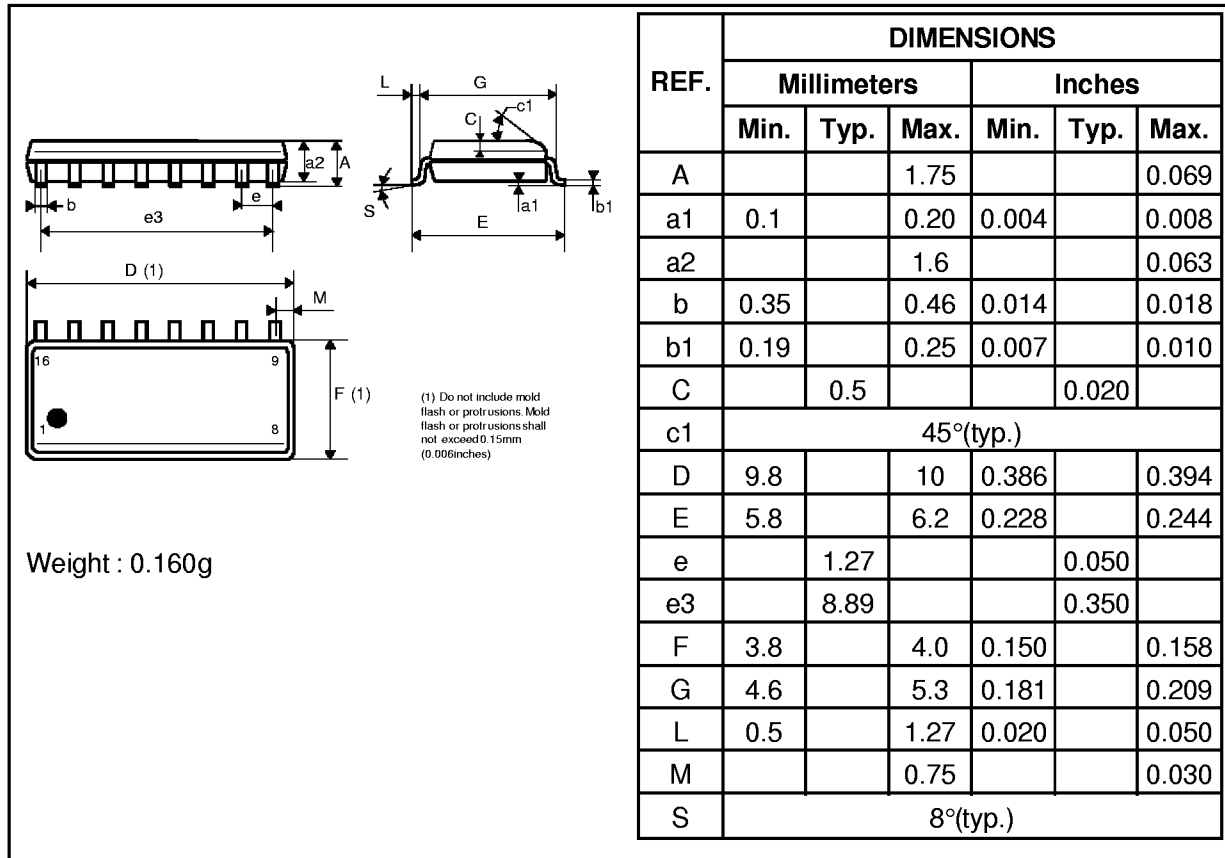


## MARKING

Type	Package	Marking
SA12B5	SO16	SA12B5
SA16B3	SO20	SA16B3
SA16B6	SSOP20	SA16B6

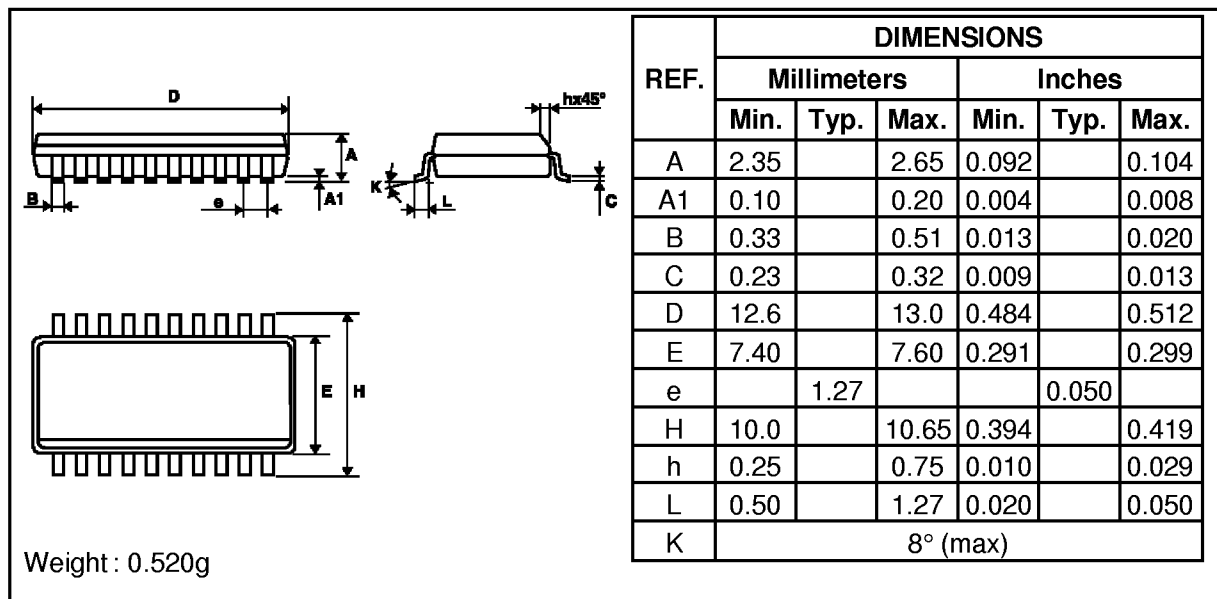
## PACKAGE MECHANICAL DATA

### SO-16

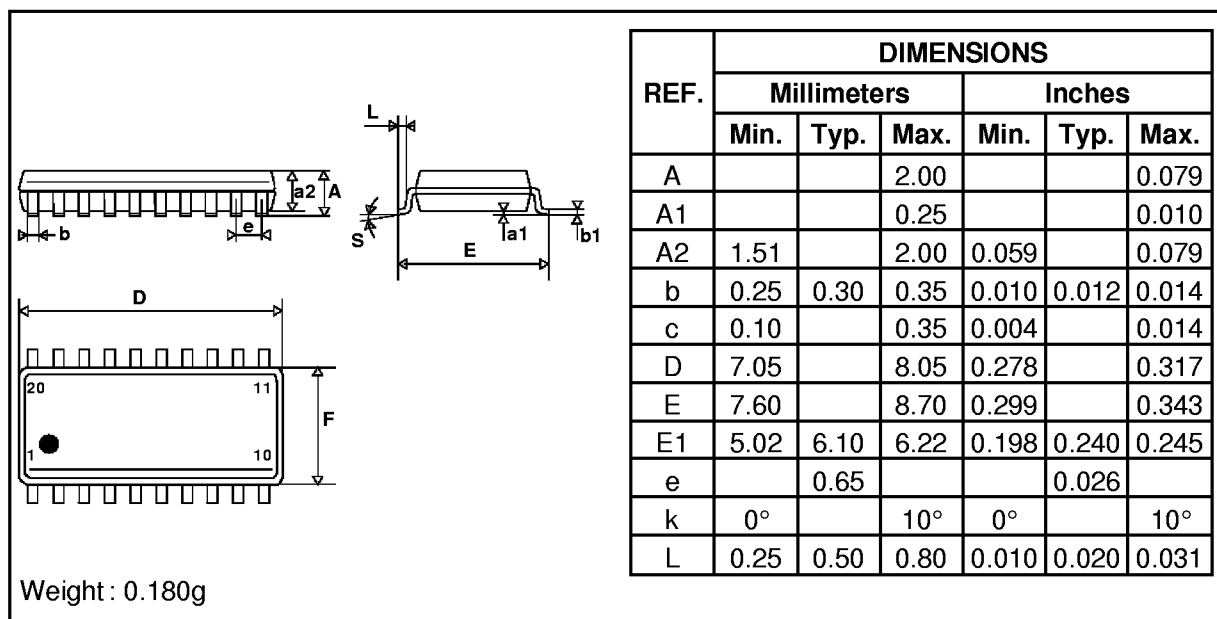


## PACKAGE MECHANICAL DATA

SO-20



## SSOP20



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